FEATURES

Available in the Texas Instruments NanoFree[™] Package

RUMENTS

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- Control Inputs VIH/VIL Levels Are Referenced to V_{CCA} Voltage
- Fully Configurable Dual-Rail Design Allows Each Port to Operate Over the Full 1.2-V to 3.6-V Power-Supply Range
- I/Os Are 4.6-V Tolerant
- Ioff Supports Partial-Power-Down Mode Operation
- Max Data Rates
 - 500 Mbps (1.8-V to 3.3-V Translation)
 - 320 Mbps (<1.8-V to 3.3-V Translation)
 - 320 Mbps (Translate to 2.5 V or 1.8 V)
 - 280 Mbps (Translate to 1.5 V)
 - 240 Mbps (Translate to 1.2 V)
- Latch-Up Performance Exceeds 100 mA Per JESD 78. Class II
- ESD Protection Exceeds JESD 22
 - 8000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

DESCRIPTION/ORDERING INFORMATION

This dual-bit noninverting bus transceiver uses two separate configurable power-supply rails. The A port is designed to track V_{CCA}. V_{CCA} accepts any supply voltage from 1.2 V to 3.6 V. The B port is designed to track V_{CCB}. V_{CCB} accepts any supply voltage from 1.2 V to 3.6 V. This allows for universal low-voltage bidirectional translation between any of the 1.2-V, 1.5-V, 1.8-V, 2.5-V, and 3.3-V voltage nodes.

T _A	PACKAGE ⁽¹⁾⁽²⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING ⁽³⁾
	NanoFree™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)	Reel of 3000	SN74AVC2T45YZPR	TD_
–40°C to 85°C	SSOP – DCT	Reel of 3000	SN74AVC2T45DCTR	DT2
	VSSOP – DCU	Reel of 3000	SN74AVC2T45DCUR	DT2_

ORDERING INFORMATION

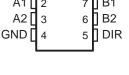
(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI (2) website at www.ti.com.

DCT: The actual top-side marking has three additional characters that designate the year, month, and assembly/test site. (3)DCU: The actual top-side marking has one additional character that designates the assembly/test site. YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free).



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. NanoFree is a trademark of Texas Instruments.





GND	D1 4	5 😡	DIR
A2	©1 3	6©	B2
A1	®1) 2	7 B2	B1
V _{CCA}	b) 4 C) 3 B) 2 A) 1	8 🖓	V _{CCB}
V _{CCA}	A1 1	8 @	V _{CC}





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DESCRIPTION/ORDERING INFORMATION (CONTINUED)

The SN74AVC2T45 is designed for asynchronous communication between two data buses. The logic levels of the direction-control (DIR) input activate either the B-port outputs or the A-port outputs. The device transmits data from the A bus to the B bus when the B-port outputs are activated and from the B bus to the A bus when the A-port outputs are activated. The input circuitry on both A and B ports always is active and must have a logic HIGH or LOW level applied to prevent excess I_{CC} and I_{CCZ}.

The SN74AVC2T45 is designed so that the DIR input is powered by V_{CCA}.

This device is fully specified for partial-power-down applications using Ioff. The Ioff circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

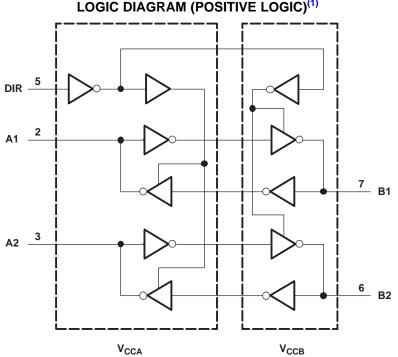
The V_{CC} isolation feature ensures that if either V_{CC} input is at GND, both ports are in the high-impedance state.

NanoFree™ package technology is a major breakthrough in IC packaging concepts, using the die as the package.

FUNCTION TABLE⁽¹⁾

(EACH TRANSCEIVER) INPUT OPERATION DIR L B data to A bus н A data to B bus

(1) Input circuits of the data I/Os always are active.



(1) Pin numbers are for the DCT and DCU packages only.

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Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CCA} V _{CCB}	Supply voltage range		-0.5	4.6	V
		I/O ports (A port)	-0.5	4.6	
VI	Input voltage range ⁽²⁾	I/O ports (B port)	-0.5	4.6	V
		Control inputs	-0.5	4.6	
V	Voltage range applied to any output in the high-impedance or power-off state $^{(2)}$	A port	-0.5	4.6	V
Vo	power-off state ⁽²⁾	B port	-0.5	4.6	V
\/) (alternational conditions) that the prime state $(2)(3)$	A port	-0.5	V _{CCA} + 0.5	V
Vo	Voltage range applied to any output in the high or low state $^{(2)(3)}$	B port	-0.5	V _{CCB} + 0.5	V
I _{IK}	Input clamp current	V ₁ < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
I _O	Continuous output current			±50	mA
	Continuous current through V _{CCA} , V _{CCB} , or GND			±100	mA
		DCT package		220	
θ_{JA}	Package thermal impedance ⁽⁴⁾	DCU package		227	°C/W
		YZP package		102	
T _{stg}	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The output positive-voltage rating may be exceeded up to 4.6 V maximum if the output current ratings are observed.

(4) The package thermal impedance is calculated in accordance with JESD 51-7.



Recommended Operating Conditions⁽¹⁾⁽²⁾⁽³⁾⁽⁴⁾⁽⁵⁾

			V _{CCI}	V _{cco}	MIN	MAX	UNIT
V _{CCA}	Supply voltage				1.2	3.6	V
V _{CCB}	Supply voltage				1.2	3.6	V
			1.2 V to 1.95 V		$V_{CCI} imes 0.65$		
V _{IH}	High-level input voltage	Data inputs ⁽⁴⁾	1.95 V to 2.7 V		1.6		V
	input voltage		2.7 V to 3.6 V		2		
			1.2 V to 1.95 V			$V_{CCI} imes 0.35$	
V _{IL}	Low-level input voltage	Data inputs ⁽⁴⁾	1.95 V to 2.7 V			0.7	V
	input voltage		2.7 V to 3.6 V			0.8	
			1.2 V to 1.95 V		$V_{CCA} imes 0.65$		
V _{IH}	High-level input voltage	DIR (referenced to V _{CCA}) ⁽⁵⁾	1.95 V to 2.7 V		1.6		V
	input voltago		2.7 V to 3.6 V		2		
			1.2 V to 1.95 V			$V_{\text{CCA}} \times 0.35$	
VIL	Low-level input voltage	DIR (referenced to V _{CCA}) ⁽⁵⁾	1.95 V to 2.7 V			0.7	V
	input voltage		2.7 V to 3.6 V			0.8	
VI	Input voltage				0	3.6	V
V	Output voltogo	Active state			0	V _{CCO}	V
Vo	Output voltage	3-state			0	3.6	v
				1.2 V		-3	
				1.4 V to 1.6 V		-6	
I _{OH}	High-level output	current		1.65 V to 1.95 V		-8	mA
				2.3 V to 2.7 V		-9	
				3 V to 3.6 V		-12	
				1.2 V		3	
				1.4 V to 1.6 V		6	
I _{OL}	Low-level output of	current		1.65 V to 1.95 V		8	mA
				2.3 V to 2.7 V		9	
				3 V to 3.6 V		12	
Δt/Δv	Input transition ris	e or fall rate				5	ns/V
T _A	Operating free-air	temperature			-40	85	°C

V_{CCI} is the V_{CC} associated with the input port.
 V_{CCO} is the V_{CC} associated with the output port.
 All unused data inputs of the device must be held at V_{CCI} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.
 For V_{CCI} values not specified in the data sheet, V_{IH} min = V_{CCI} × 0.7 V, V_{IL} max = V_{CCI} × 0.3 V.
 For V_{CCI} values not specified in the data sheet, V_{IH} min = V_{CCA} × 0.7 V, V_{IL} max = V_{CCA} × 0.3 V.



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Electrical Characteristics⁽¹⁾⁽²⁾

over recommended operating free-air temperature range (unless otherwise noted)

	METER	TEST CON		N	V		T _A = 25°C		–40°C to 85	S°C	UNIT	
PARA	METER	TEST CONE	DITIONS	V _{CCA}	V _{CCB}	MIN	ТҮР	MAX	MIN	MAX	UNI	
		I _{OH} = -100 μA		1.2 V to 3.6 V	1.2 V to 3.6 V				V _{CCO} - 0.2 V			
		$I_{OH} = -3 \text{ mA}$		1.2 V	1.2 V		0.95					
V _{OH}		I _{OH} =6 mA	$V_{I} = V_{IH}$	1.4 V	1.4 V				1.05		V	
		I _{OH} = -8 mA		1.65 V	1.65 V				1.2			
		I _{OH} = -9 mA		2.3 V	2.3 V				1.75			
		$I_{OH} = -12 \text{ mA}$		3 V	3 V				2.3			
		$I_{OL} = 100 \ \mu A$		1.2 V to 3.6 V	1.2 V to 3.6 V					0.2		
		$I_{OL} = 3 \text{ mA}$		1.2 V	1.2 V		0.25					
V		$I_{OL} = 6 \text{ mA}$	$V_{I} = V_{IL}$	1.4 V	1.4 V					0.35	V	
V _{OL}		$I_{OL} = 8 \text{ mA}$	$v_{I} = v_{IL}$	1.65 V	1.65 V					0.45	v	
		$I_{OL} = 9 \text{ mA}$		2.3 V	2.3 V					0.55		
		I _{OL} = 12 mA		3 V	3 V					0.7		
I _I [DIR	$V_I = V_{CCA}$ or GI	ND	1.2 V to 3.6 V	1.2 V to 3.6 V		±0.025	±0.25		±1	μA	
, A	A port	V_1 or $V_0 = 0$ to	261/	0 V	0 to 3.6 V		±0.1	±1		±5	- uA	
l _{off} E	B port	v_1 or $v_0 = 0$ to	3.0 V	0 to 3.6 V	0 V		±0.1	±1		±5	μΑ	
, E	B port	$V_{O} = V_{CCO}$ or G	ND	0 V	3.6 V		±0.5	±2.5		±5		
l _{oz}	A port	$V_I = V_{CCI}$ or GN	ID	3.6 V	0 V		±0.5	±2.5		±5	μA	
				1.2 V to 3.6 V	1.2 V to 3.6 V					10		
I _{CCA}		$V_I = V_{CCI}$ or GN	ID, I _O = 0	0 V	3.6 V					-2	μA	
				3.6 V	0 V					10		
				1.2 V to 3.6 V	1.2 V to 3.6 V					10		
I _{CCB}		$V_I = V_{CCI}$ or GN	ID, I _O = 0	0 V	3.6 V					10	μA	
				3.6 V	0 V					-2		
l _{CCA} + l (see Ta		$V_{I} = V_{CCI} \text{ or } GN$	$ID, I_O = 0$	1.2 V to 3.6 V	1.2 V to 3.6 V					20	μA	
	Control inputs	V _I = 3.3 V or G	ND	3.3 V	3.3 V		2.5				pF	
	A or B port	$V_{0} = 3.3 \text{ V or } G$	SND	3.3 V	3.3 V		6				pF	

 $\begin{array}{ll} \mbox{(1)} & V_{CCO} \mbox{ is the } V_{CC} \mbox{ associated with the output port.} \\ \mbox{(2)} & V_{CCI} \mbox{ is the } V_{CC} \mbox{ associated with the input port.} \end{array}$

Switching Characteristics

over recommended operating free-air temperature range, $V_{CCA} = 1.2 \text{ V}$ (see Figure 1)

		o 1		00/1				
PARAMETER	FROM	то	V _{CCB} = 1.2 V	V _{CCB} = 1.5 V	V _{CCB} = 1.8 V	V _{CCB} = 2.5 V	V _{CCB} = 3.3 V	UNIT
FARAIVIETER	(INPUT)	(OUTPUT)	ТҮР	TYP	TYP	TYP	TYP	UNIT
t _{PLH}	А	Р	3.1	2.6	2.4	2.2	2.2	5
t _{PHL}	A	В	3.1	2.6	2.4	2.2	2.2	ns
t _{PLH}	В	•	3.4	3.1	3	2.9	2.9	5
t _{PHL}	Б	A	3.4	3.1	3	2.9	2.9	ns
t _{PHZ}	DID	•	5.2	5.2	5.1	5	4.8	
t _{PLZ}	DIR	A	5.2	5.2	5.1	5	4.8	ns
t _{PHZ}	DID	P	5	4	3.8	2.8	3.2	
t _{PLZ}	DIR	В	5	4	3.8	2.8	3.2	ns
t _{PZH} ⁽¹⁾	DID	•	8.4	7.1	6.8	5.7	6.1	
t _{PZL} ⁽¹⁾	DIR	A	8.4	7.1	6.8	5.7	6.1	ns
t _{PZH} ⁽¹⁾	סוס	_	8.3	7.8	7.5	7.2	7	
t _{PZL} ⁽¹⁾	DIR	В	8.3	7.8	7.5	7.2	7	ns

(1) The enable time is a calculated value, derived using the formula shown in the enable times section.

Switching Characteristics

over recommended operating free-air temperature range, V_{CCA} = 1.5 V \pm 0.1 V (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)		V _{CCB} = ± 0.1		V _{ССВ} = ± 0.1		V _{ССВ} = ± 0.2		$V_{CCB} = 3.3 V \\ \pm 0.3 V$		UNIT																	
	(INFUT)	(001201)	ТҮР	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX																		
t _{PLH}	А	В	2.8	0.7	5.4	0.5	4.6	0.4	3.7	0.3	3.5	ns																	
t _{PHL}	A	Б	2.8	0.7	5.4	0.5	4.6	0.4	3.7	0.3	3.5	115																	
t _{PLH}	В	А	2.7	0.8	5.4	0.7	5.2	0.6	4.9	0.5	4.7	20																	
t _{PHL}	Б	A	2.7	0.8	5.4	0.7	5.2	0.6	4.9	0.5	4.7	ns																	
t _{PHZ}	DIR	^	3.9	1.3	8.5	1.3	7.8	1.1	7.7	1.4	7.6	20																	
t _{PLZ}	DIR	A	3.9	1.3	8.5	1.3	7.8	1.1	7.7	1.4	7.6	ns																	
t _{PHZ}	DIR	В	4.7	1.1	7	1.4	6.9	1.2	6.9	1.7	7.1	20																	
t _{PLZ}	DIR	Б	4.7	1.1	7	1.4	6.9	1.2	6.9	1.7	7.1	ns																	
t _{PZH} ⁽¹⁾	DIR	^	7.4		12.4		12.1		11.8		11.8	20																	
t _{PZL} ⁽¹⁾	DIR	A	7.4		12.4		12.1		11.8		11.8	ns																	
t _{PZH} ⁽¹⁾	חוח	Р	6.7		13.9		12.4		11.4		11.1	20																	
t _{PZL} ⁽¹⁾	DIR	DIR	DIR	DIR	DIR	DIR	DIR	DIR	DIR	DIR	DIR	DIR	DIR	DIR	DIR	DIR	DIR	DIR	DIR B	6.7		13.9		12.4		11.4		11.1	ns

(1) The enable time is a calculated value, derived using the formula shown in the enable times section.

Switching Characteristics

over recommended operating free-air temperature range, V_{CCA} = 1.8 V ± 0.15 V (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB} = 1.2 V	V _{ССВ} = ± 0.7	1.5 V I V	V _{ССВ} = ± 0.1		V _{ССВ} = ± 0.2		V _{CCB} = 3.3 V ± 0.3 V		UNIT	
	(INFUT)	(001201)	TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX		
t _{PLH}	А	В	2.7	0.5	5.2	0.4	4.3	0.2	3.4	0.2	3.1	20	
t _{PHL}	A	Б	2.7	0.5	5.2	0.4	4.3	0.2	3.4	0.2	3.1	ns	
t _{PLH}	В	•	2.4	0.7	4.7	0.5	4.4	0.5	4	0.4	3.8	20	
t _{PHL}	Б	A	2.4	0.7	4.7	0.5	4.4	0.5	4	0.4	3.8	ns	
t _{PHZ}	סוס	•	3.7	1.3	8.1	0.7	6.9	1.4	5.3	1.1	5.2	20	
t _{PLZ}	DIR	A	3.7	1.3	8.1	0.7	6.9	1.4	5.3	1.1	5.2	ns	
t _{PHZ}	DIR	В	4.4	1.3	5.8	1.3	5.9	0.8	5.7	1.5	5.9	20	
t _{PLZ}	DIR	Б	4.4	1.3	5.8	1.3	5.9	0.8	5.7	1.5	5.9	ns	
t _{PZH} ⁽¹⁾	DIR	А	6.8		10.5		10.3		9.7		9.7	20	
t _{PZL} ⁽¹⁾	DIR	A	6.8		10.5		10.3		9.7		9.7	ns	
t _{PZH} ⁽¹⁾	סוס		6.4		13.3		11.2		8.7		8.3		
t _{PZL} ⁽¹⁾	DIR	DIR	В	6.4		13.3		11.2		8.7		8.3	ns 3

(1) The enable time is a calculated value, derived using the formula shown in the *enable times* section.

Switching Characteristics

over recommended operating free-air temperature range, V_{CCA} = 2.5 V \pm 0.2 V (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB} = 1.2 V	V _{ССВ} = ± 0.1	1.5 V I V	V _{CCB} = ± 0.1		V _{ССВ} = ± 0.2		$V_{CCB} = 3.3 V \\ \pm 0.3 V$		UNIT																
	(INFUT)	(001201)	TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX																	
t _{PLH}	А	В	2.6	0.4	4.9	0.2	4	0.2	3	0.2	2.6	ns																
t _{PHL}	A	Б	2.6	0.4	4.9	0.2	4	0.2	3	0.2	2.6	115																
t _{PLH}	В	А	2.1	0.6	3.8	0.5	3.4	0.4	3	0.3	2.8																	
t _{PHL}	Б	A	2.1	0.6	3.8	0.5	3.4	0.4	3	0.3	2.8	ns																
t _{PHZ}	DIR	А	2.4	0.7	7.9	0.8	6.4	0.8	5	0.5	4.3	20																
t _{PLZ}	DIR	A	2.4	0.7	7.9	0.8	6.4	0.8	5	0.5	4.3	ns																
t _{PHZ}	DIR	В	3.8	1	4.3	0.6	4.3	0.5	4.2	1.1	4.1	20																
t _{PLZ}	DIR	Б	3.8	1	4.3	0.6	4.3	0.5	4.2	1.1	4.1	ns																
t _{PZH} ⁽¹⁾	DIR	^	5.9		8.5		7.7		7.2		6.9																	
t _{PZL} ⁽¹⁾	DIR	A	5.9		8.5		7.7		7.2		6.9	ns																
t _{PZH} ⁽¹⁾	פוס	P	5		12.8		10.4		8		6.9	20																
t _{PZL} ⁽¹⁾	DIR	DIR	DIR	DIR	DIR	DIR	DIR	DIR	DIR	DIR	DIR	DIR	DIR	DIR	DIR	DIR	DIR	В	5		12.8		10.4		8		6.9	ns

(1) The enable time is a calculated value, derived using the formula shown in the enable times section.

Switching Characteristics

over recommended operating free-air temperature range, V_{CCA} = 3.3 V \pm 0.3 V (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CCB} = 1.2 V	V _{CCB} = ± 0.7		V _{CCB} = ± 0.1		V _{CCB} = ± 0.2		V_{CCB} = 3.3 V ± 0.3 V		UNIT			
	(INFUT)	(001F01)	TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX				
t _{PLH}	А	В	2.5	0.3	4.7	0.2	3.8	0.2	2.8	0.2	2.4	20			
t _{PHL}	A	В	2.5	0.3	4.7	0.2	3.8	0.2	2.8	0.2	2.4	ns			
t _{PLH}	В	А	2.1	0.6	3.6	0.4	3.1	0.3	2.6	0.3	2.4	ns			
t _{PHL}	Б	A	2.1	0.6	3.6	0.4	3.1	0.3	2.6	0.3	2.4	115			
t _{PHZ}	פוס	^	2.9	1.1	8	1	6.5	1.3	4.7	1.2	4	20			
t _{PLZ}	DIR	DIR A	2.9	1.1	8	1	6.5	1.3	4.7	1.2	4	ns			
t _{PHZ}	DIR	В	3.4	0.5	6.6	0.3	5.6	0.3	4.6	1.1	4.2	20			
t _{PLZ}	DIR	Б	3.4	0.5	6.6	0.3	5.6	0.3	4.6	1.1	4.2	ns			
t _{PZH} ⁽¹⁾	DIR	А	5.5		10.2		8.7		7.2		6.6	20			
t _{PZL} ⁽¹⁾	DIK	A	5.5		10.2		8.7		7.2		6.6	ns			
t _{PZH} ⁽¹⁾	חוח	Р	5.4		12.7		10.3		7.5		6.4	20			
t _{PZL} ⁽¹⁾	DIR	DIR	В	В	R B	5.4		12.7		10.3		7.5		6.4	ns

(1) The enable time is a calculated value, derived using the formula shown in the enable times section.

Operating Characteristics

 $T_A = 25^{\circ}C$

P	ARAMETER	TEST CONDITIONS	V _{CCA} = V _{CCB} = 1.2 V	V _{CCA} = V _{CCB} = 1.5 V	V _{CCA} = V _{CCB} = 1.8 V	V _{CCA} = V _{CCB} = 2.5 V	V _{CCA} = V _{CCB} = 3.3 V	UNIT
		CONDITIONO	TYP	TYP	TYP	TYP	TYP	
C (1)	A-port input, B-port output	$C_{L} = 0,$	3	3	3	3	4	Ľ
C _{pdA} ⁽¹⁾	B-port input, A-port output	f = 10 MHz, $t_r = t_f = 1 \text{ ns}$	12	13	13	14	15	pF
C _{pdB} ⁽¹⁾	A-port input, B-port output	$C_{L} = 0,$	12	13	13	14	15	۶Ē
UpdB∵	B-port input, A-port output	f = 10 MHz, $t_r = t_f = 1 \text{ ns}$	3	3	3	3	4	pF

(1) Power-dissipation capacitance per transceiver

Power-Up Considerations

A proper power-up sequence always should be followed to avoid excessive supply current, bus contention, oscillations, or other anomalies. To guard against such power-up problems, take the following precautions:

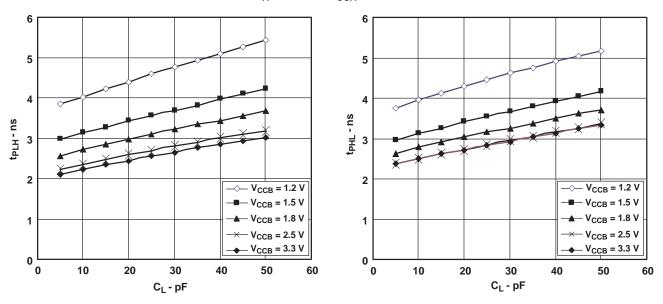
- 1. Connect ground before any supply voltage is applied.
- 2. Power up V_{CCA}.
- 3. V_{CCB} can be ramped up along with or after V_{CCA} .

V		V _{CCA}								
V _{CCB}	0 V	1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	UNIT			
0 V	0	<0.5	<0.5	<0.5	<0.5	<0.5				
1.2 V	<0.5	<1	<1	<1	<1	1				
1.5 V	<0.5	<1	<1	<1	<1	1				
1.8 V	<0.5	<1	<1	<1	<1	<1	μA			
2.5 V	<0.5	1	<1	<1	<1	<1				
3.3 V	<0.5	1	<1	<1	<1	<1				

Table 1. Typical Total Static Power Consumption (I_{CCA} + I_{CCB})

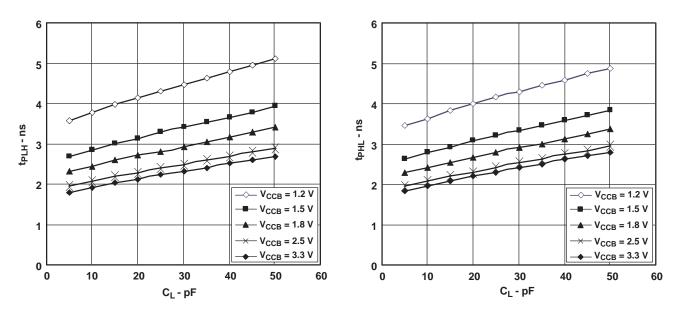


TYPICAL CHARACTERISTICS

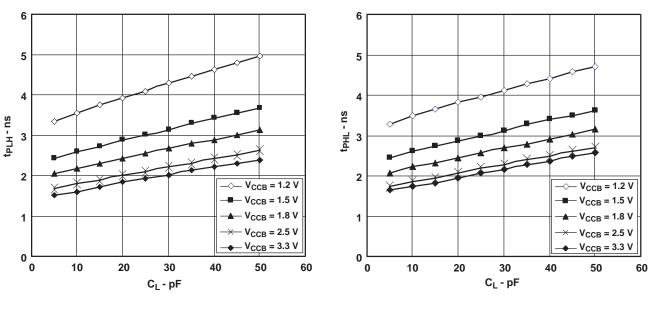


TYPICAL PROPAGATION DELAY (A to B) vs LOAD CAPACITANCE, $T_{\rm A}$ = 25°C, $V_{\rm CCA}$ = 1.2 V

TYPICAL PROPAGATION DELAY (A to B) vs LOAD CAPACITANCE, $T_{\rm A}$ = 25°C, $V_{\rm CCA}$ = 1.5 V

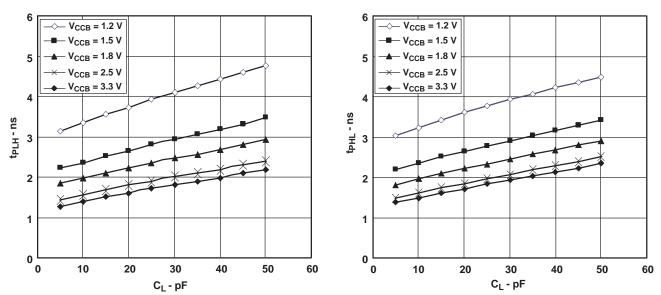


TYPICAL CHARACTERISTICS



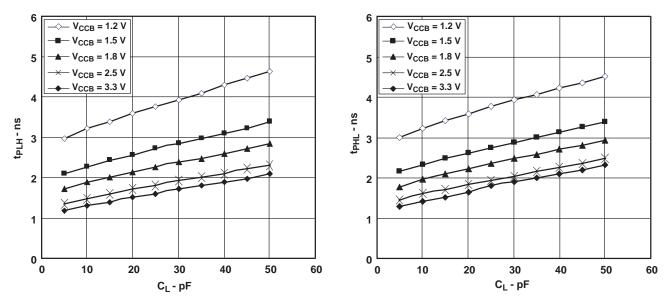
TYPICAL PROPAGATION DELAY (A to B) vs LOAD CAPACITANCE, $T_{\rm A}$ = 25°C, $V_{\rm CCA}$ = 1.8 V

TYPICAL PROPAGATION DELAY (A to B) vs LOAD CAPACITANCE, $T_{\rm A}$ = 25°C, $V_{\rm CCA}$ = 2.5 V



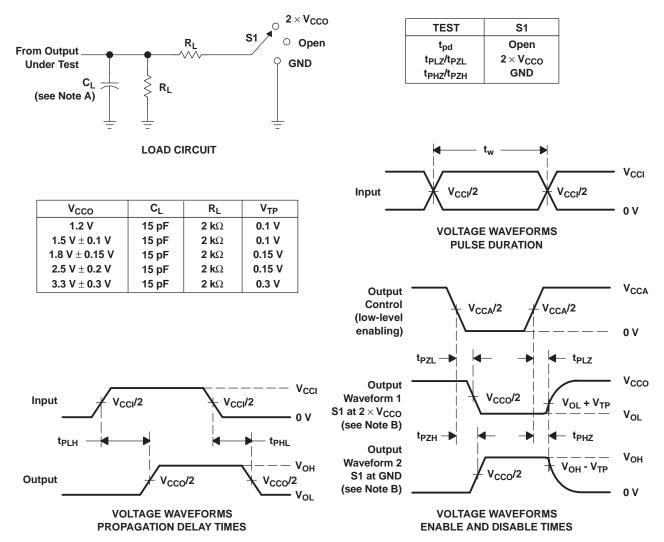


TYPICAL CHARACTERISTICS



TYPICAL PROPAGATION DELAY (A to B) vs LOAD CAPACITANCE, $T_{\rm A}$ = 25°C, $V_{\rm CCA}$ = 3.3 V

SCES531J-DECEMBER 2003-REVISED JUNE 2007



PARAMETER MEASUREMENT INFORMATION

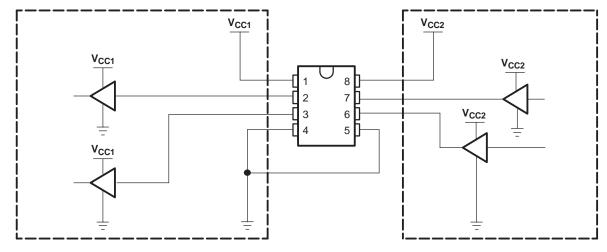
- NOTES: A. CL includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_Q = 50 Ω, dv/dt ≥ 1 V/ns.
 - D. The outputs are measured one at a time, with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - F. t_{PZL} and t_{PZH} are the same as t_{en} .
 - G. t_{PLH} and t_{PHL} are the same as t_{pd} .
 - H. V_{CCI} is the V_{CC} associated with the input port.
 - I. V_{CCO} is the V_{CC} associated with the output port.

Figure 1. Load Circuit and Voltage Waveforms



APPLICATION INFORMATION

Figure 2 is an example circuit of the SN74AVC2T45 used in a unidirectional logic level-shifting application.



SYSTEM-1

SYSTEM-2

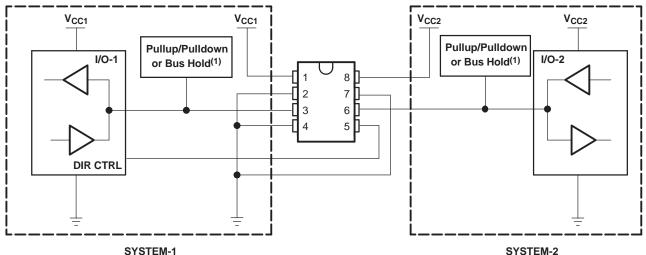
PIN	NAME	FUNCTION	DESCRIPTION					
1	V _{CCA}	V _{CC1}	SYSTEM-1 supply voltage (1.2 V to 3.6 V)					
2	A1	OUT1	Output level depends on V _{CC1} voltage.					
3	A2	OUT2	Output level depends on V _{CC1} voltage.					
4	GND	GND	Device GND					
5	DIR	DIR	The GND (low-level) determines B-port to A-port direction.					
6	B2	IN2	Input threshold value depends on V _{CC2} voltage.					
7	B1	IN1	Input threshold value depends on V _{CC2} voltage.					
8	V _{CCB}	V _{CC2}	SYSTEM-2 supply voltage (1.2 V to 3.6 V)					

Figure 2. Unidirectional Logic Level-Shifting Application

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APPLICATION INFORMATION

Figure 3 shows the SN74AVC2T45 used in a bidirectional logic level-shifting application. Since the SN74AVC2T45 does not have an output-enable (OE) pin, the system designer should take precautions to avoid bus contention between SYSTEM-1 and SYSTEM-2 when changing directions.



SYSTEM-2

Following is a sequence that illustrates data transmission from SYSTEM-1 to SYSTEM-2 and then from SYSTEM-2 to SYSTEM-1.

STATE	DIR CTRL	I/O-1	I/O-2	DESCRIPTION
1	Н	Out	In	SYSTEM-1 data to SYSTEM-2
2	н	Hi-Z	Hi-Z	SYSTEM-2 is getting ready to send data to SYSTEM-1. I/O-1 and I/O-2 are disabled. The bus-line state depends on pullup or pulldown. ⁽¹⁾
3	L	Hi-Z	Hi-Z	DIR bit is flipped. I/O-1 and I/O-2 still are disabled. The bus-line state depends on pullup or pulldown. ⁽¹⁾
4	L	In	Out	SYSTEM-2 data to SYSTEM-1

(1) SYSTEM-1 and SYSTEM-2 must use the same conditions, i.e., both pullup or both pulldown.

Figure 3. Bidirectional Logic Level-Shifting Application

Enable Times

Calculate the enable times for the SN74AVC2T45 using the following formulas:

- t_{P7H} (DIR to A) = t_{PI7} (DIR to B) + t_{PIH} (B to A)
- t_{PZL} (DIR to A) = t_{PHZ} (DIR to B) + t_{PHL} (B to A)
- t_{PZH} (DIR to B) = t_{PLZ} (DIR to A) + t_{PLH} (A to B)
- t_{PZL} (DIR to B) = t_{PHZ} (DIR to A) + t_{PHL} (A to B)

In a bidirectional application, these enable times provide the maximum delay from the time the DIR bit is switched until an output is expected. For example, if the SN74AVC2T45 initially is transmitting from A to B, then the DIR bit is switched; the B port of the device must be disabled before presenting it with an input. After the B port has been disabled, an input signal applied to it appears on the corresponding A port after the specified propagation delay.



20-May-2013

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74AVC2T45DCTR	ACTIVE	SM8	DCT	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	DT2 Z	Samples
SN74AVC2T45DCTRE4	ACTIVE	SM8	DCT	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	DT2 Z	Samples
SN74AVC2T45DCTRG4	ACTIVE	SM8	DCT	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	DT2 Z	Samples
SN74AVC2T45DCTT	ACTIVE	SM8	DCT	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	DT2 Z	Samples
SN74AVC2T45DCTTE4	ACTIVE	SM8	DCT	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	DT2 Z	Samples
SN74AVC2T45DCTTG4	ACTIVE	SM8	DCT	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	DT2 Z	Samples
SN74AVC2T45DCUR	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	(DT2R ~ T2) DZ	Samples
SN74AVC2T45DCURE4	ACTIVE	US8	DCU	8		TBD	Call TI	Call TI	-40 to 85		Samples
SN74AVC2T45DCURG4	ACTIVE	US8	DCU	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	DT2R	Samples
SN74AVC2T45DCUT	ACTIVE	US8	DCU	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	DT2R	Samples
SN74AVC2T45DCUTE4	ACTIVE	US8	DCU	8		TBD	Call TI	Call TI	-40 to 85		Samples
SN74AVC2T45DCUTG4	ACTIVE	US8	DCU	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	DT2R	Samples
SN74AVC2T45YZPR	ACTIVE	DSBGA	YZP	8	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	(TD7 ~ TDN)	Samples

⁽¹⁾ The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.



20-May-2013

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

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OTHER QUALIFIED VERSIONS OF SN74AVC2T45 :

Automotive: SN74AVC2T45-Q1

NOTE: Qualified Version Definitions:

• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AVC2T45DCUR	US8	DCU	8	3000	180.0	9.0	2.05	3.3	1.0	4.0	8.0	Q3
SN74AVC2T45DCUR	US8	DCU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3
SN74AVC2T45DCURG4	US8	DCU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3
SN74AVC2T45DCUTG4	US8	DCU	8	250	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3
SN74AVC2T45YZPR	DSBGA	YZP	8	3000	178.0	9.2	1.02	2.02	0.63	4.0	8.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

14-Mar-2013



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AVC2T45DCUR	US8	DCU	8	3000	182.0	182.0	20.0
SN74AVC2T45DCUR	US8	DCU	8	3000	202.0	201.0	28.0
SN74AVC2T45DCURG4	US8	DCU	8	3000	202.0	201.0	28.0
SN74AVC2T45DCUTG4	US8	DCU	8	250	202.0	201.0	28.0
SN74AVC2T45YZPR	DSBGA	YZP	8	3000	220.0	220.0	35.0

MECHANICAL DATA

MPDS049B - MAY 1999 - REVISED OCTOBER 2002

DCT (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion

D. Falls within JEDEC MO-187 variation DA.



DCT (R-PDSO-G8) PLASTIC SMALL OUTLINE Example Board Layout Example Stencil Design (Note C,E) (Note D) - 6x0,65 - 6x0,65 8x0,25-8x1,55 3,40 3,40 Non Solder Mask Defined Pad Example Pad Geometry -0,30 (Note C) 1,60 Example -0,07 Non-solder Mask Opening All Around (Note E) 4212201/A 10/11

NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



DCU (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.

D. Falls within JEDEC MO-187 variation CA.



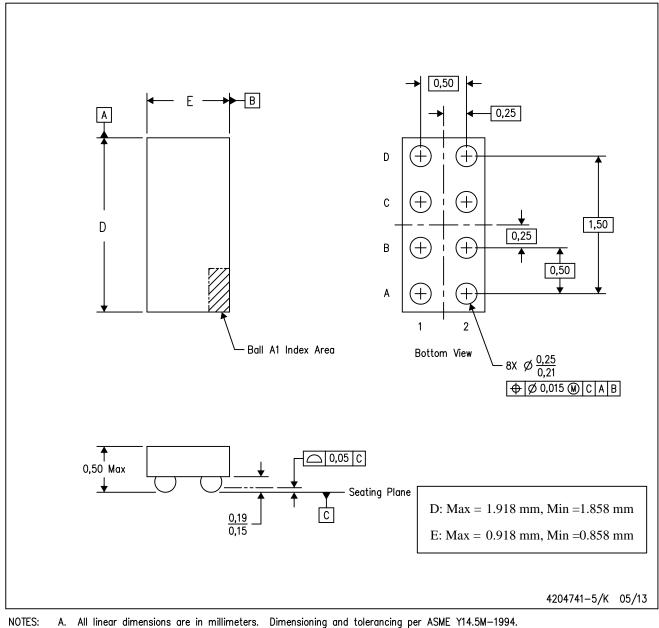


- NOTES: A. All linear dimensions are in millimeters. В. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



YZP (R-XBGA-N8)

DIE-SIZE BALL GRID ARRAY



- A. All linear dimensions are in millimeters. Dimension B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.

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